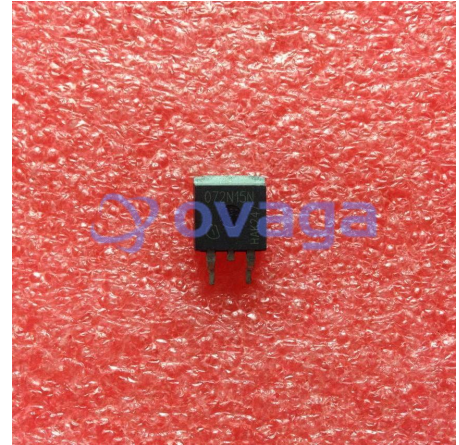


Trans MOSFET N-CH 150V 100A Automotive 3-Pin(2+Tab) D2PAK T/R

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-263-3
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for IPB072N15N3G or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

IPB072N15N3G is a type of power MOSFET (Metal Oxide Semiconductor Field-Effect Transistor) manufactured by Infineon Technologies AG, a German semiconductor manufacturer.

Features

Drain-Source Voltage (V_{ds}): 150V

Continuous Drain Current (I_d): 72A

$R_{ds(on)}$ Max (at >

Package Type: TO-263-3 (D2PAK)

Application

DC-DC converters

Motor control

Switching power supplies

Audio amplifiers

Lighting control



Related Products



[IPP60R070CFD7](#)

Infineon Technologies Corporation
TO-220-3



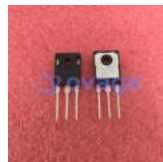
[IPB180N06S4-H1](#)

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PG-TO263-7-3



[IPG20N04S4-12](#)

Infineon Technologies Corporation
TDSON-8



[IPW65R080CFD](#)

Infineon Technologies Corporation
TO-247



[IPD25N06S4L-30](#)

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PG-TO252-3



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TO-220-3



[IPD70R1K4P7S](#)

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TO252-3